PRELIMINARY DATA SHEET



BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC8158K$

RF UP-CONVERTER WITH AGC FUNCTION + IF QUADRATURE MODULATOR IC FOR DIGITAL MOBILE COMMUNICATION SYSTEMS

DESCRIPTION

The μ PC8158K is a silicon microwave monolithic integrated circuit designed as quadrature modulator for digital mobile communication systems. This MMIC consists of 0.8 GHz to 1.5 GHz up-converter and 100 MHz to 300 MHz quadrature modulator which are equipped with AGC and power save functions. This configuration suits to IF modulation system. The package is 28-pin QFN suitable for high density mounting. The chip is manufactured using NEC's. 20 GHz fr silicon bipolar process NESATTM III to realize low power consumption. Consequently the μ PC8158K can contribute to make RF blocks smaller size, higher performance and lower power consumption.

FEATURES

- Supply voltage: Vcc = 2.7 to 4.0 V, Icc = 28 mA @ Vcc = 3.0 V
- Built-in LPF suppresses spurious multipled by TX local (LO1)
- AGC amplifier is installed in local port of up converter: GCR = 35 dB MIN. @ fout = 1.5 GHz
- Excellent performance: Padj = -65 dBc TYP. @ Δf = ±50 kHz, EVM = 1.2 % rms TYP.
- External IF filter can be applied between modulator output and up converter input terminal.

APPLICATIONS

• Digital cellular phones (PDC800M, PDC1.5G and so on)

ORDERING INFORMATION

Part Number	Package	Supplying Form
μPC8158K-E1	28-pin plastic QFN (5.1 × 5.5 × 0.95 mm)	Embossed tape 12 mm wide. Pin 1 is in pull-out direction. QTY 2.5 kp/Reel.

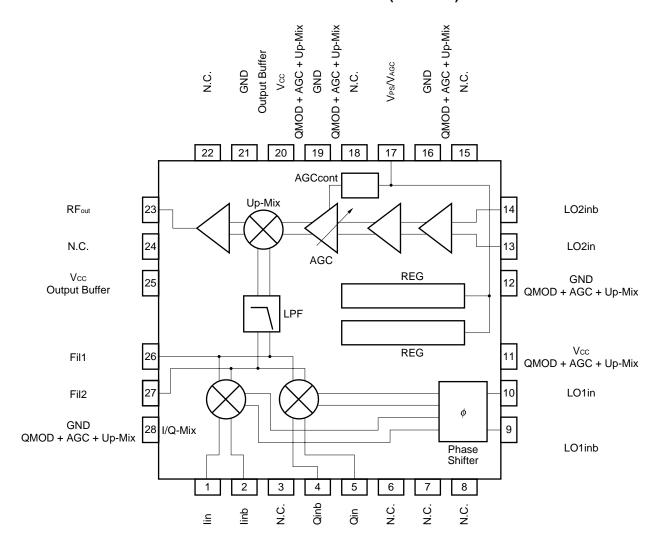
Remark To order evaluation samples, please contact your local NEC sales office. (Part number for sample order: μ PC8158K)

Caution Electro-static sensitive device

The information in this document is subject to change without notice.



INTERNAL BLOCK DIAGRAM AND PIN CONNECTIONS (TOP View)





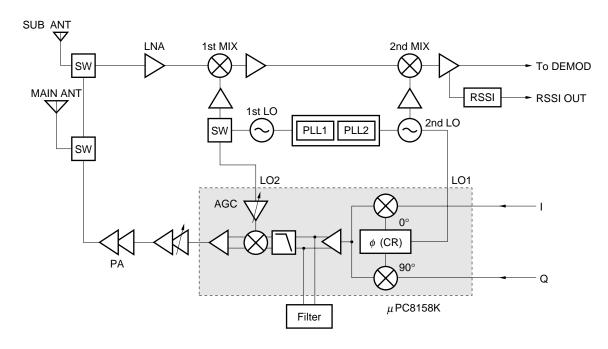
QUADRATURE MODULATOR SERIES

Part Number	Functions	Icc (mA)	f _{LO1in} (MHz)	f _{MODout} (MHz)	Up-Converter frequency (MHz)	Phase Shifter	Package	Application
μPC8101GR	150 MHz Quad. Mod	15/@ 2.7 V	100 to 300	50 to 150	External	F/F	20-pin	CT-2, etc.
μPC8104GR	RF Up-Converter + IF Quad. Mod	28/@ 3.0 V	100 t	o 400	900 to 1 900	Doubler + F/F	SSOP (225 mil)	Digital Comm.
μPC8105GR	400 MHz Quad. Mod	16/@ 3.0 V	100 t	o 400	External		16-pin SSOP (225 mil)	
μPC8110GR	1GHz Direct Quad. Mod	24/@ 3.0 V	800 to	800 to 1 000			20-pin SSOP (225 mil)	PDC800 MHz, etc.
μPC8125GR	RF Up-Converter + IF Quad. Mod + AGC	36/@ 3.0 V	220 t	220 to 270				PHS
μPC8126GR	900 MHz Direct Quad.	35/@ 3.0 V	915 t	915 to 960				PDC800 MHz
μPC8126K	Mod with Offset-Mixer		889 t	o 960	(LO pre-mixer)		28-pin QFN	
μPC8129GR	×2LO IF Quad. Mod + RF Up-Converter	28/@ 3.0 V	200 to 800	100 to 400	800 to 1900	F/F	20-pin SSOP (225 mil)	GSM, DCS1800, etc.
μPC8139GR-7JH	Transceiver IC (1.9 GHz Indirect Quad. Mod + RX-IF + IF VCO)	TX: 32.5 RX: 4.8 /@ 3.0 V	220 to 270		1 800 to 2 000	CR	30-pin TSSOP (225 mil)	PHS
μPC8158K	RF Up-Converter + IF Quad. Mod + AGC	28/@ 3.0 V	100 t	o 300	800 to 1 500		28-pin QFN	PDC800 M/ 1.5 G

For outline of the quadrature modulator series, please refer to the application note 'Usage of μ PC8101, 8104, 8105, 8125, 8129' (Document No. P13251E) and so on.

SYSTEM APPLICATION EXAMPLE

[PDC800 MHz/1.5 GHz]





ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Rating	Unit
Supply Voltage	Vcc	Pin11, 20 and 25, T _A = +25°C	5.0	V
Power Save and AGC Control Pin Applied Voltage	Vps/Vagc	Pin17, T _A = +25°C	5.0	V
Power Dissipation	PD	$T_A = +85^{\circ}C^{\text{Note}}$	430	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Note Mounted on double sided copper clad $50 \times 50 \times 1.6$ mm epoxy glass PWB.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	Pin11, 20 and 25	2.7	3.0	4.0	V
Power Save Voltage	VPS	Pin17	0	_	0.3	V
AGC Control Voltage	Vagces	Pin17	1.0	-	2.5	V
Operating Ambient Temperature	TA		-30	+25	+80	°C
Up-converter RF Output Frequency	f RFout		800	-	1500	MHz
LO2 Input Frequency	f LO2in	PLO2in = -15 dBm	600	-	1750	MHz
I/Q Input Frequency	f _{I/Qin}	V _{I/Qin} = 500 mV _{P-P} MAX. (Differential input)	DC	-	10	MHz
LO1 Input Level	P _{LO1in}		-18	-15	-12	dBm
LO2 Input Level	P _{LO2in}		-18	-15	-12	dBm
I/Q Input Amplitude	VI/Qin	I, Ib, Q, Qb each	_	420	500	mV _{P-P}
Up-converter Input Frequency	fupconin		100	-	300	MHz
Modulator Output Frequency	fMODout					
LO1 Input Frequency	f LO1in	PLO1in = -15 dBm				



ELECTRICAL CHARACTERISTICS

Conditions (Unless otherwise specified):

 $T_A = +25 \, ^{\circ}C$, $V_{CC1} = V_{CC2} = V_{CC3} = 3.0 \, \text{V}$, $V_{PS}/V_{AGC} = 2.5 \, \text{V}$,

I/Q (DC) = Ib/Qb (DC) = Vcc/2 = 1.5 V, $V_{I/Ibin} = V_{Q/Qbin} = 500 \text{ mV}_{P-P}$ (each), $f_{I/Qin} = 2.625 \text{ kHz}$,

 π /4DQPSK wave input, transmission rate 42 kbps, filter roll-off α = 0.5,

Modulation Pattern: <0000>

 $f_{LO1in} = 178.05 \text{ MHz}, P_{LO1in} = -15 \text{ dBm}$

 $f_{LO2in} = 1619.05 \text{ MHz}, P_{LO2in} = -15 \text{ dBm}$

 $f_{RFout} = 1441 MHz - f_{I/Qin}$

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit			
UP-CONVERTER + QUADRATURE MODULATOR TOTAL									
Total Circuit Current	ICC (TOTAL)	No input signal	23.7	28	37.6	mA			
Total Circuit Current at Power Save Mode	ICC (PS) TOTAL	V _{PS} ≤ 0.5 V (Low), No input signal	-	0.3	10	μΑ			
Total Output Power 1	P _{RFout} 1	Vagc = 2.5 V	-15	-11.5	-8	dBm			
Total Output Power 2	P _{RFout} 2	Vagc = 1.0 V	-56.5	-52	-46.5	dBm			
LO Carrier Leak	LOL	fLOL = fLO1 + fLO2	-	-40	-30	dBc			
Image Rejection (Side Band Leak)	ImR		-	-40	-30	dBc			
I/Q 3rd order distortion	IM _{3 (I/Q)}		-	-50	-30	dBc			
AGC Gain Control Range	GCR	$V_{AGC} = 2 \text{ V} \rightarrow 1 \text{ V}$	35	40	-	dB			
Error Vector Magnitude	EVM	MOD Pattern: PN9	-	1.2	3.0	%rms			
Adjacent channel interference	P _{adj}	$\Delta f = \pm 50 \text{ kHz},$ MOD Pattern: PN9	-	-65	-60	dBc			
Spurious suppression	Pout (8fLO1)	$fLO1 \times 8$, $fLO1 \times 8$ (image) ^{Note}	-	-70	-65	dBc			
Power Save Rise Time	T _{PS} (Rise)	$V_{PS (Low)} ightarrow V_{PS (High)}$	_	2	5	μs			
Power Save Fall Time	TPS (Fall)	$V_{PS (High)} ightarrow V_{PS (Low)}$	_	2	5	μs			
I/Q input impedance	Z _{I/Q}	Between pin I/Ib, Q/Qb	80	200	_	kΩ			
I/Q input bias current	l _{I/Q}	Between pin I/Ib, Q/Qb	_	5	13	μΑ			
LO1 input VSWR	Z _{LO1}	fLO1 = 100 M to 300 MHz	-	1.5:1	_	_			

Note Without external LC between Fil1 and Fil2 pin on this frequency conditions.

Spectrum analyzer conditions: VBW = 300 Hz, RBW = 300 Hz.

Remark Electrical characteristics in this document is described for 1.5 GHz system.



PIN EXPLANATIONS

Pin No.	Symbol	Supply Voltage (V)	Pin Voltage (V)	Function and Application	Internal Equivalent Circuit
1	lin	Vcc/2	T	Input for I signal. This input impedance is 200 k Ω . In the case of that I/Q input signals are single ended, amplitude of the signal is 500 m V _{P-P} max.	T T T T T T T T T T T T T T T T T T T
2	linb	Vcc/2	1	Input for I signal. This input impedance is 200 k Ω . In the case of that I/Q input signals are single ended, Vcc/2 biased DC signal should be input. In the case of the I/Q input signals are differential, amplitude of the signal is 500 m VP-P max.	
3	N.C.	_	-	This pin is not connected to internal circuit. This pin should be opened or grounded.	
4	Qinb	Vcc/2	-	Input for Q signal. This input impedance is 200 k Ω . In the case of that I/Q input signals are single ended, amplitude of the signal is 500 m V _{P-P} max.	
5	Qin	Vcc/2	1	Input for I signal. This input impedance is 200 k Ω . In the case of that I/Q input signals are single ended, Vcc/2 biased DC signal should be input. In case of the I/Q input signals are differential, amplitude of the signal is 500 m VP-P max.	4
6	N.C.	-	-	These pins are not connected to	
7	N.C.			internal circuit. These pins should be opened or grounded.	
8	N.C.			,	
9	LO1inb	-	2.98	Bypass pin of modulator's local input. This pin should be decoupled with 330 pF capacitor.	9
10	LO1in	-	2.98	Local signal input for modulator. This pin must be coupled with DC cut capacitor 330 pF and should be terminated with 51 Ω resistor.	* * * * * * * * * * * * * * * * * * * *
11	Vcc	2.7 to 4.0	-	Supply voltage pin for modulator, up-converter and AGC circuits.	

Note Pin Voltages are measured on Vcc = 3.0 V.



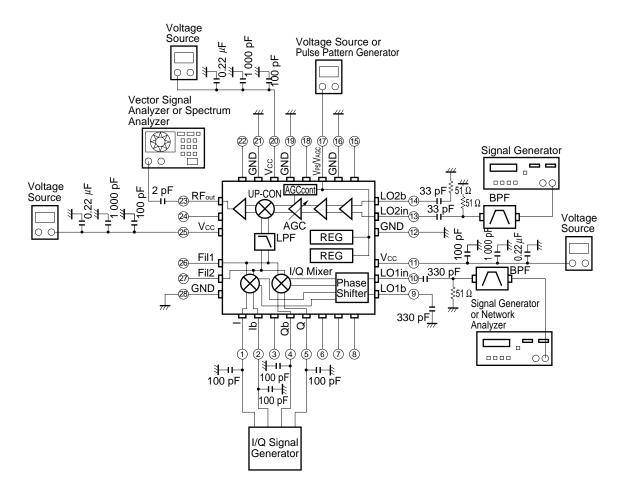
Pin No.	Symbol	Supply Voltage (V)	Pin Voltage (V)	Function and Application	Internal Equivalent Circuit
12	GND	0	I	Ground pin for modulator, up- converter and AGC circuits. This pin should be grounded with minimum inductance. Form the ground pattern as widely as possible to minimize ground impedance.	
13	LO2in	-	1.8	Local signal input for modulator. This pin must be coupled with DC cut capacitor 33 pF and should be terminated with 51 Ω resistor.	13 (14)
14	LO2inb	-	1.8	Bypass pin of up-converter's local signal input. This pin should be decoupled with 33 pF capacitor.	
15	N.C.	-	-	This pin is not connected to internal circuit. This pin should be opened or grounded.	
16	GND	0	Г	Ground pin for modulator, up- converter and AGC circuits. This pin should be grounded with minimum inductance.	
17	Vps/Vagc	Vps/Vagc		Power save control pin for modulator, up-converter and AGC circuits. This pin also assigned as gain control pin for AGC circuits. Operation status with applied voltages are as follows. VPS/VAGC (V) STATE 0 to 0.4 OFF (Sleep Mode) 1 to 2.5 On (AGC Mode)	REG AGC Cont
18	N.C.	-	-	This pin is not connected to internal circuit. This pin should be opened or grounded.	
19	GND	0	-	Ground pin for modulator, up- converter and AGC circuits. This pin should be grounded with minimum inductance.	
20	Vcc	2.7 to 4.0	_	Supply voltage pin for modulator, up-converter and AGC circuits.	
21	GND	0	-	Ground pin for RF output buffer. This pin should be grounded with minimum inductance.	

Note Pin Voltages are measured on Vcc = 3.0 V.

Pin No.	Symbol	Supply Voltage (V)	Pin Voltage (V)	Function and Application	Internal Equivalent Circuit
22	N.C.	-	ı	This pin is not connected to internal circuit. This pin should be opened or grounded.	
23	RFout	-	1.75	RF output pin. This pin is emitter follower which is low impedance output port. This pin can be easily matched to 50 Ω impedance using external coupling and decoupling capacitors.	External (3) 1 1 1 1 1 1 1 1 1
24	N.C.	-	-	These pins are not connected to internal circuit. These pins should be opened or grounded.	
25	Vcc	2.7 to 4.0	1	Supply voltage pin for RF output buffer.	
26	Fil1	_	2.76	External inductor and capacitor can	
27	Fil2	-	2.76	supress harmonics spurious of LO1 frequency. LC value should be determined according to LO1 input frequency and suppression level.	External 26 27
28	GND	0	ı	Ground pin for modulator, up- converter and AGC circuits. This pin should be grounded with minimum inductance. Form the ground pattern as widely as possible to minimize ground impedance.	

Note Pin Voltages are measured on Vcc = 3.0 V.

TEST CIRCUIT



TEST CONDITIONS

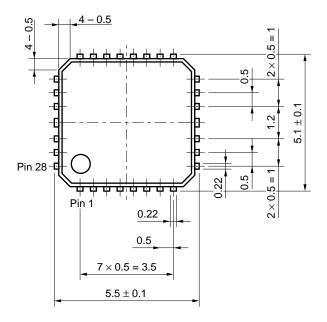
 $f_{LO1in} = 178.05 \text{ MHz}, P_{LO1in} = -15 \text{ dBm}$

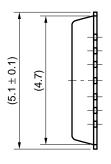
 $f_{LO2in} = 1619.05 \text{ MHz}, P_{LO2in} = -15 \text{ dBm}$

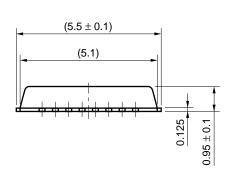
 $f_{RFout} = 1441 \text{ MHz} - f_{I/Qin}$

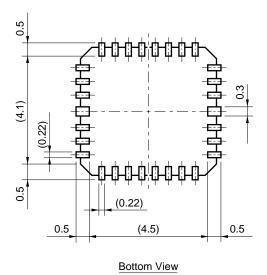
PACKAGE DIMENSIONS

28 pin plastic QFN (UNIT: mm)











RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

μPC8158K

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 2, Exposure limit ^{Note} : None	IR35-00-2
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit ^{Note} : None	-

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).



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systems, anti-crime systems, safety equipment and medical equipment (not specifically designed

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